**Bright-Dark Exciton Splitting in Monolayer MoSe2**

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**Introduction**

 Atomically thin group-VIB transition metal dichalcogenides (TMDs) have recently attracted vast interest as a new class of gapped semiconductors. When TMDs are thinned down from bulk to monolayers, a striking change in their electronic structure is the crossover from indirect to a direct band gap at the degenerate but inequivalent K and –K valleys at the corners of the hexagonal Brillouin zone. Since the conduction band (CB) edges at K/-K valleys are spin-split, the lowest energy excitonic state could be optically bright or dark depending on the nature of relevant spin-allowed or spin-forbidden transitions. Application of an external in-plane magnetic field mixes the components of the spin-split CB, thus brightening the originally dark excitons. Magnetic field brightening of dark excitons has been observed in WSe2 monolayers [1], although the magnetic field induced splitting of bright and dark exciton in TMDs remains unexplored.

**Experimental**

 The experiments were performed on a MoSe2 monolayer encapsulated by h-BN. The photoluminescence and reflectance spectra were measured in Voigt geometry using a direct-optics micro-spectroscopy setup coupled either to the 14.5T (EMR facility) or 17.5T (DC field facility) superconducting magnet.

**Results and Discussion**

 The PL spectrum of MoSe2/hBN features two peaks corresponding to the emission from bright neutral and negatively charged excitons. The in-plane magnetic field brightens the spin-forbidden neutral dark exciton making it clearly distinguishable at B>10T. The energy separation between bright and dark excitons varies quadratically with the magnetic field strength, consistent with theoretical expectations, in which the CB spin is linearly perturbed by the in-plane magnetic field. However, this simple model does not explain two important experimental observations: (i) the asymmetry of bright and dark exciton branches, (ii) the deviation from the B2 behavior of exciton branches that appears in reflectance spectra at high fields above 14-15T.

**Fig.1.**  Splitting of dark and bright excitons of monolayer MoSe2 as a function of in-plane magnetic field. Symbols represent the energies of PL peaks measured with non-resonant excitation.

**Conclusions**

PL and reflectance spectroscopy measurements on h-BN encapsulated MoSe2 monolayers performed with in-plane magnetic fields up to 17.5T reveal the effect of bright-dark exciton splitting. Further measurements at higher fields are needed to investigate the high-field anomalies of the splitting.

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**References**

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